

August 1984 Revised February 1999

MM74HC4060 14 Stage Binary Counter

General Description

The MM74HC4060 is a high speed binary ripple carry counter. These counters are implemented utilizing advanced silicon-gate CMOS technology to achieve speed performance similar to LS-TTL logic while retaining the low power and high noise immunity of CMOS.

The MM74HC4060 is a 14-stage counter, which device increments on the falling edge (negative transition) of the input clock, and all their outputs are reset to a low level by applying a logical high on their reset input. The MM74HC4060 also has two additional inputs to enable easy connection of either an RC or crystal oscillator.

This device is pin equivalent to the CD4060. All inputs are protected from damage due to static discharge by protection diodes to $V_{\rm CC}$ and ground.

Features

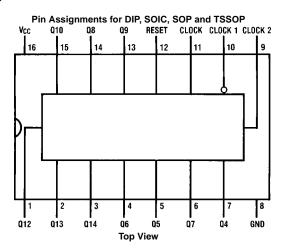
- Typical propagation delay: 16 ns
- Wide operating voltage range: 2–6V
- Low input current: 1 μA maximum
- Low quiescent current: 80 µA maximum (74 Series)
- Output drive capability: 10 LS-TTL loads

Ordering Code:

Order Number	Package Number	Package Description
MM74HC4060M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4060SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4060MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4060N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	-1.5 to V_{CC} +1.5 V
DC Output Voltage (V _{OUT})	-0.5 to V_{CC} +0.5V
Clamp Diode Current (I _{CD})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage			
(V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_{r}, t_{f}) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Maximum Ratings are those values be	eyond whi	ch damag	e to the

device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating: plastic "N" package:

-12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

(Soldering 10 seconds)

Symbol	Parameter		Conditions	V _{cc}	T _A = 25°C		T _A = -40 to 85°C	T _A = -55 to 125°C	Units
Symbol				• 66	Тур		Guaranteed Limits		
V _{IH}	Minimum HIGH			2.0V		1.5	1.5	1.5	V
	Level Voltage			4.5V		3.15	3.15	3.15	V
	(Not Applicable t	o Pins 9 & 10)		6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW I	Level		2.0V		0.5	0.5	0.5	V
	Input Voltage			4.5V		1.35	1.35	1.35	V
	(Not Applicable t	o Pins 9 & 10)		6.0V		1.8	1.8	1.8	V
V _{OH}	Minimum HIGH I	_evel	$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage		$ I_{OUT} \le 20 \ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
				4.5V	4.5	4.4	4.4	4.4	V
				6.0V	6.0	5.9	5.9	5.9	V
		Except Pins	$V_{IN} = V_{IH}$ or V_{IL}						
		9 & 10	$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
			$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
		Pins	$V_{IN} = V_{IH}$ or V_{IL}			3.98	3.84	3.7	V
		9 & 10	$ I_{OUT} = 0.4 \text{ mA}$			5.48	5.34	5.2	V
			$ I_{OUT} = 0.52 \text{ mA}$						
V _{OL}	Maximum LOW Level		$V_{IN} = V_{IH}$ or V_{IL}						
	Output Voltage		$ I_{OUT} \le 20 \ \mu A$	2.0V	0	0.1	0.1	0.1	V
				4.5V	0	0.1	0.1	0.1	V
				6.0V	0	0.1	0.1	0.1	V
		Except Pins	$V_{IN} = V_{IH}$ or V_{IL}						
		9 & 10	$ I_{OUT} \le 4.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
			$ I_{OUT} \le 5.2 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
		Pins	$V_{IN} = V_{IH}$ or V_{IL}			0.26	0.33	0.4	V
		9 & 10	$ I_{OUT} = 0.4 \text{ mA}$			0.26	0.33	0.4	V
			$ I_{OUT} = 0.52 \text{ mA}$						
I _{IN}	Maximum Input Current		V _{IN} = V _{CC} or GND	6.0V		±0.1	±1.0	±1.0	μΑ
I _{CC}	Maximum Quiescent		V _{IN} = V _{CC} or GND						
	Supply Current		$I_{OUT} = 0 \mu A$	6.0V		8.0	80	160	μΑ

260°C

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH} , and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5V$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 15$ pF, $t_r = t_f = 6$ ns

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
f _{MAX}	Maximum Clock Frequency			30	MHz
t _{PHL} , t _{PLH}	Maximum Propagation	(Note 5)	40	20	ns
	Delay to Q ₄				
t _{PHL} , t _{PLH}	Maximum Propagation		16	40	ns
	Delay to any Q				
t _{REM}	Minimum Reset		10	20	ns
	Removal Time				
t _W	Minimum Pulse Width		10	16	ns

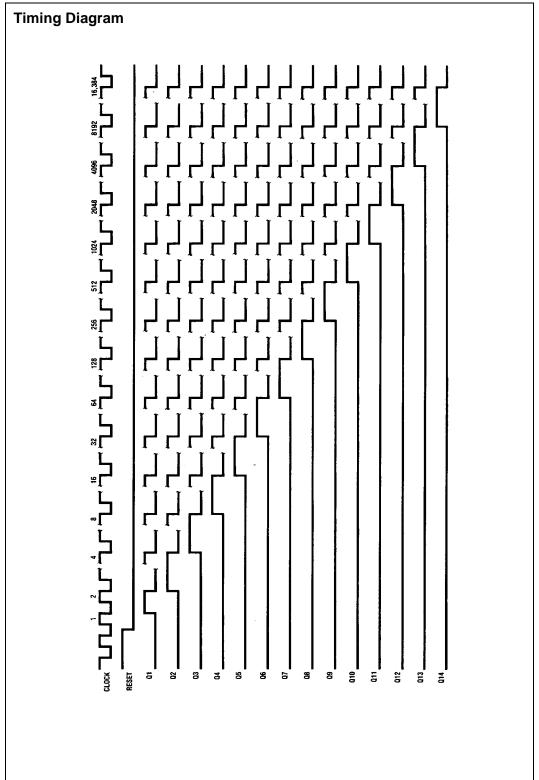
AC Electrical Characteristics

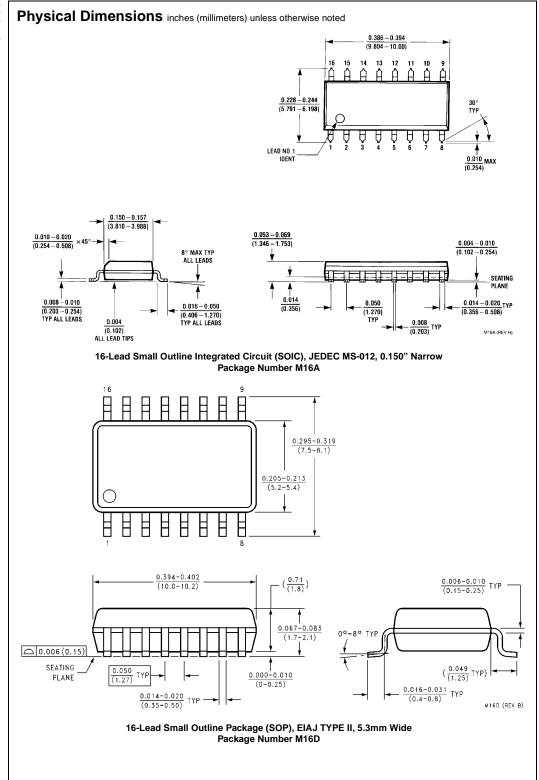
 $\rm V_{CC}\,{=}\,2.0V$ to 6.0V, $\rm C_L\,{=}\,50$ pF, $\rm t_f\,{=}\,t_f\,{=}\,6$ ns (unless otherwise specified)

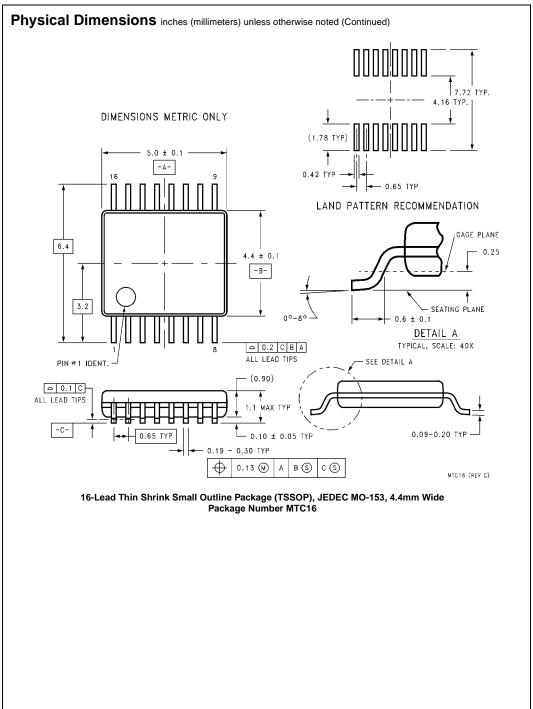
Symbol	Parameter	Conditions	v _{cc}	T _A = 25°C		$T_A = -40 \text{ to } 85^{\circ}\text{C}$	T _A = -55 to 125°C	Units
Cyllibol				Тур	Guaranteed Limits			
f _{MAX}	Maximum Operating		2.0V		6	5	4	MHz
	Frequency		4.5V		30	24	20	MHz
			6.0V		35	28	24	MHz
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	120	380	475	171	ns
	Delay Clock to Q ₄		4.5V	42	76	95	114	ns
			6.0V	35	65	81	97	ns
t _{PHL}	Maximum Propagation		2.0V	72	240	302	358	ns
	Delay Reset to any Q		4.5V	24	48	60	72	ns
			6.0V	20	41	51	61	ns
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V		125	156	188	ns
	Delay Between Stages		4.5V		25	31	38	ns
	Q _n to Q _{n+1}		6.0V		21	26	31	ns
t _{REM}	Minimum Reset		2.0V		100	125	150	ns
	Removal Time		4.5V		20	25	30	ns
			6.0V		17	21	25	ns
t _W	Minimum Pulse Width		2.0V		80	100	120	ns
			4.5V		16	20	24	ns
			6.0V		14	17	20	ns
t _r , t _f	Maximum Input Rise and		2.0V		1000	1000	1000	ns
	Fall Time		4.5V		500	500	500	ns
			6.0V		400	400	400	ns
t _{THL} , t _{TLH}	Maximum Output Rise		2.0V	30	75	95	110	ns
	and Fall Time		4.5V	10	15	19	22	ns
			6.0V	9	13	16	19	ns
C _{PD}	Power Dissipation	(per package)		55				pF
	Capacitance (Note 6)							
C _{IN}	Maximum Input			5	10	10	10	pF
	Capacitance							

Note 5: Typical Propagation delay time to any output can be calculated using: $t_p = 17+12(N-1)$ ns; where N is the number of the output, Q_W , at $V_{CC} = 5V$.

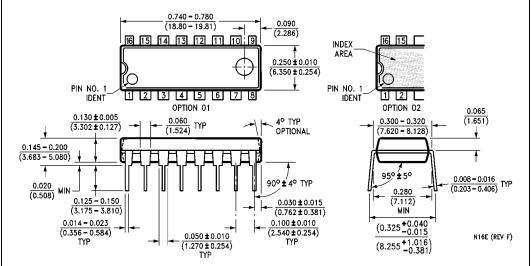
Note 6: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 \ f+I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f+I_{CC}$.







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16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N16E

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